



Schottky Barrier Rectifiers

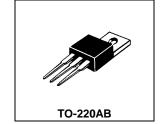
Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

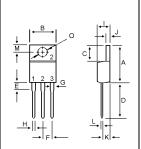
- ¡ Low Forward Voltage.
- I Low Switching noise.
- i High Current Capacity
- i Guarantee Reverse Avalanche.
- i Guard-Ring for Stress Protection.
- i Low Power Loss & High efficiency.
- i 150¢J Operating Junction Temperature
- i Low Stored Charge Majority Carrier Conduction.
- 7 Plastic Material used Carries Underwriters Laboratory

Flammability Classification 94V-O

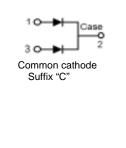
SCHOTTKY BARRIER RECTIFIERS

16 AMPERES 30-60 VOLTS





| DIM | MILLIMETERS | | | | |
|-------|-------------|-------|--|--|--|
| DIIVI | MIN | MAX | | | |
| Α | 14.68 | 15.32 | | | |
| В | 9.78 | 10.42 | | | |
| С | 5.02 | 6.52 | | | |
| D | 13.06 | 14.62 | | | |
| Е | 3.57 | 4.07 | | | |
| F | 2.42 | 2.66 | | | |
| G | 1.12 | 1.36 | | | |
| Н | 0.72 | 0.96 | | | |
| - 1 | 4.22 | 4.98 | | | |
| J | 1.14 | 1.38 | | | |
| K | 2.20 | 2.98 | | | |
| L | 0.33 | 0.55 | | | |
| М | 2.48 | 2.98 | | | |
| 0 | 3.70 | 3.90 | | | |



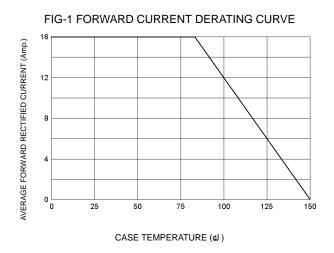
MAXIMUM RATINGS

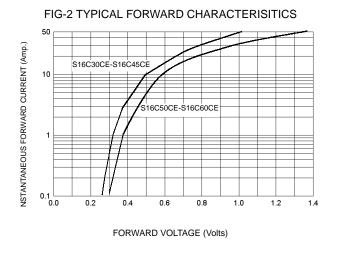
| | Symbol | S16C | | | | | | |
|--|--|-------------|------|------|------|------|------|------|
| Characteristic | | 30CE | 35CE | 40CE | 45CE | 50CE | 60CE | Unit |
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 30 | 35 | 40 | 45 | 50 | 60 | V |
| RMS Reverse Voltage | $V_{R(RMS)}$ | 21 | 25 | 28 | 32 | 35 | 42 | V |
| Average Rectifier Forward Current Total Device (Rated V _R), T _C =100¢J | I _{F(AV)} | 8.0 16 | | | | Α | | |
| Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz) | I _{FM} | 16 | | | | | Α | |
| Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz) | I _{FSM} | 150 | | | | А | | |
| Operating and Storage Junction Temperature Range | | -65 to +150 | | | | | ¢J | |

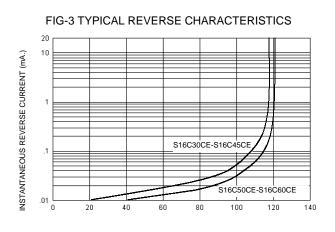
ELECTRIAL CHARACTERISTICS

| Characteristic | Symbol | S16C | | | | | | 1144 |
|--|----------------|--------------|------|------|----------|------|------|------|
| Characteristic | | 30CE | 35CE | 40CE | 45CE | 50CE | 60CE | Unit |
| $\begin{aligned} &\text{Maximum Instantaneous Forward Voltage} \\ &\text{(I}_F = &8.0 \text{ Amp T}_C = 25 \text{ dJ}) \\ &\text{(I}_F = &8.0 \text{ Amp T}_C = 125 \text{ dJ}) \end{aligned}$ | V _F | 0.57 0.48 | | | 70 58 | V | | |
| Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25 d$) (Rated DC Voltage, $T_C = 125 d$) | I _R | 0.5 20 | | | | mA | | |

S16C30CE Thru S16C60CE







PERCENT OF RATED REVERSE VOLTAGE (dM)

